Schottky Barrier Diode

DB2X41500L

Unit: mm

Panasonic

DB2X41500L

Silicon epitaxial planar type

For frequency rectification

■ Features

- · Low forward voltage VF
- Forward current (Average) IF(AV) = 3 A rectification is possible
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)
- Marking Symbol: AD

■ Packaging

Embossed type (Thermo-compression sealing): 3 000 pcs / reel (standard)

1.6		0. 13			
2					
	3.5				
1 0.	<u>55</u>	0.8			
Cathode Anode					
Panasonic	Mini2-F4-B				
JEITA	SC-109D				
Code	SOD-123				

■ Absolute Maximum Ratings Ta = 25 °C

Parameter	Symbol	Rating	Unit
Reverse voltage	VR	40	V
Forward current (Average) *1	IF(AV)	3.0	Α
Non-repetitive peak forward surge current	IFSM	50 ^{*2}	Α
Non-repetitive peak forward surge current	IFSIVI	15 ^{*3}	Α
Junction temperature	Tj	125	°C
Operating ambient temperature	Topr	-40 to +85	°C
Storage temperature	Tstg	-55 to +125	°C

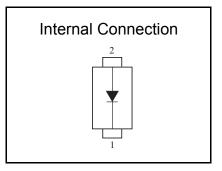
Note: *1 TI = 60 °C / DC

Established: 2010-02-26

: 2013-04-24

Revised

- *2 Rectangle wave 1 cycle (Pulse width = 50 μs, non-repetitive peak current)
- *3 50 Hz sine wave 1 cycle (Non-repetitive peak current)



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■ Electrical Characteristics Ta = 25 °C ± 3 °C

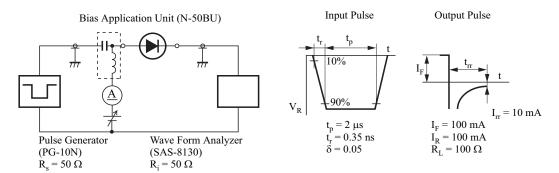
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	VF1	IF = 1.0 A		0.35	0.44	V
	VF2	IF = 3.0 A		0.47	0.55	
Reverse current	IR	VR = 40V		40	200	μA
Terminal capacitance	Ct	VR = 10 V, f = 1 MHz		70		pF
Reverse recovery time *1	trr	IF = IR = 100 mA		25		ns
		Irr = 10 mA, RL = 100 Ω		23		

- Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 Measuring methods for Diodes.
 - 2. This product is sensitive to electric shock (static electricity, etc.). Due attention must be paid on the charge of a human body and the leakage of current from the operating equipment.
 - 3. *1 trr test circuit

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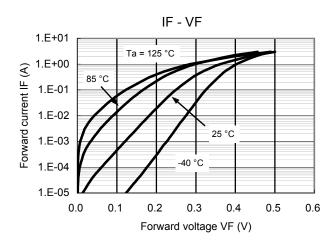


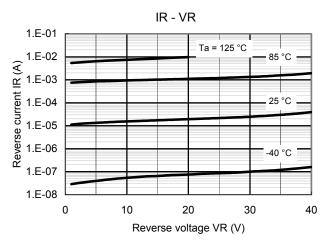
Schottky Barrier Diode

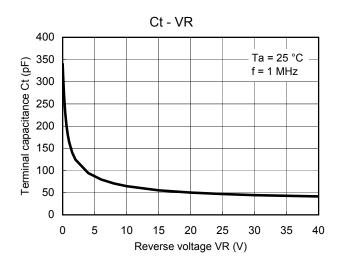
DB2X41500L

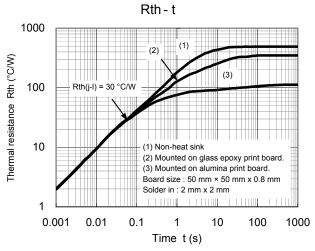
Panasonic

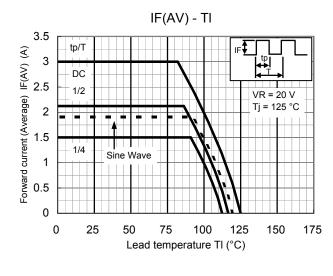
Technical Data (reference)

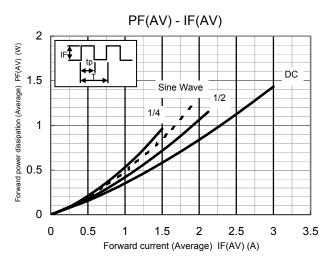












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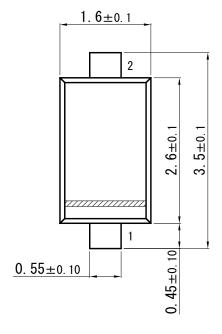
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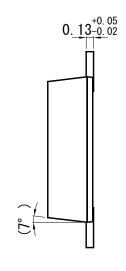
Schottky Barrier Diode

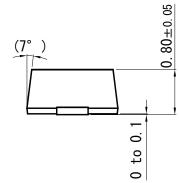
DB2X41500L

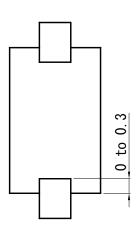
Mini2-F4-B



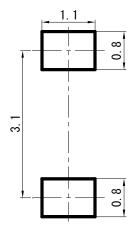








■ Land Pattern (Reference) (Unit: mm)



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